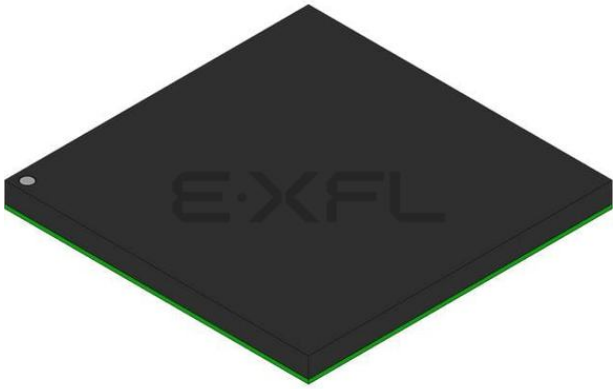

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Understanding Embedded - Microprocessors

Embedded microprocessors are specialized computing chips designed to perform specific tasks within an embedded system. Unlike general-purpose microprocessors found in personal computers, embedded microprocessors are tailored for dedicated functions within larger systems, offering optimized performance, efficiency, and reliability. These microprocessors are integral to the operation of countless electronic devices, providing the computational power necessary for controlling processes, handling data, and managing communications.

Applications of Embedded - Microprocessors

Embedded microprocessors are utilized across a broad spectrum of applications, making them indispensable in

Details	
Product Status	Obsolete
Core Processor	PowerPC e300c2
Number of Cores/Bus Width	1 Core, 32-Bit
Speed	266MHz
Co-Processors/DSP	Communications; QUICC Engine
RAM Controllers	DDR, DDR2
Graphics Acceleration	No
Display & Interface Controllers	-
Ethernet	10/100Mbps (3)
SATA	-
USB	USB 2.0 (1)
Voltage - I/O	1.8V, 2.5V, 3.3V
Operating Temperature	0°C ~ 105°C (TA)
Security Features	-
Package / Case	516-BBGA
Supplier Device Package	516-PBGA (27x27)
Purchase URL	https://www.e-xfl.com/pro/item?MUrl=&PartUrl=mpc8323vraddc

1.1.2 Serial Interfaces

The MPC8323E serial interfaces are as follows:

- Support for one UL2 interface with 31 multi-PHY addresses (MPC8323E and MPC8323 only)
- Support for up to three 10/100 Mbps Ethernet interfaces using MII or RMII
- Support for up to four T1/E1/J1/E3 or DS-3 serial interfaces (TDM)
- Support for dual UART and SPI interfaces and a single I^2C interface

1.2 QUICC Engine Block

The QUICC Engine block is a versatile communications complex that integrates several communications peripheral controllers. It provides on-chip system design for a variety of applications, particularly in communications and networking systems. The QUICC Engine block has the following features:

- One 32-bit RISC controller for flexible support of the communications peripherals
- Serial DMA channel for receive and transmit on all serial channels
- Five universal communication controllers (UCCs) supporting the following protocols and interfaces (not all of them simultaneously):
  - 10/100 Mbps Ethernet/IEEE 802.3® standard
  - IP support for IPv4 and IPv6 packets including TOS, TTL, and header checksum processing
  - ATM protocol through UTOPIA interface (note that the MPC8321 and MPC8321E do not support the UTOPIA interface)
  - HDLC /transparent up to 70-Mbps full-duplex
  - HDLC bus up to 10 Mbps
  - Asynchronous HDLC
  - UART
  - BISYNC up to 2 Mbps
  - QUICC multi-channel controller (QMC) for 64 TDM channels
- One UTOPIA interface (UPC1) supporting 31 multi-PHYs (MPC8323E- and MPC8323-specific)
- Two serial peripheral interfaces (SPI). SPI2 is dedicated to Ethernet PHY management.
- Four TDM interfaces
- Thirteen independent baud rate generators and 19 input clock pins for supplying clocks to UCC serial channels
- Four independent 16-bit timers that can be interconnected as two 32-bit timers

The UCCs are similar to the PowerQUICC II peripherals: SCC (BISYNC, UART, and HDLC bus) and FCC (fast Ethernet, HDLC, transparent, and ATM).

Table 11. Reset Signals DC Electrical Characteristics (continued)

Characteristic	Symbol	Condition	Min	Max	Unit	Notes
Input current	I_{IN}	$0 V \le V_{IN} \le OV_{DD}$	—	±5	μA	—

Note:
1. This specification applies when operating from 3.3 V supply.

6 DDR1 and DDR2 SDRAM

This section describes the DC and AC electrical specifications for the DDR1 and DDR2 SDRAM interface of the MPC8323E. Note that DDR1 SDRAM is D*n*_GV_{DD}(typ) = 2.5 V and DDR2 SDRAM is D*n*_GV_{DD}(typ) = 1.8 V. The AC electrical specifications are the same for DDR1 and DDR2 SDRAM.

6.1 DDR1 and DDR2 SDRAM DC Electrical Characteristics

Table 12 provides the recommended operating conditions for the DDR2 SDRAM component(s) of the MPC8323E when D*n*_GV_{DD}(typ) = 1.8 V.

Table 12. DDR2 SDRAM DC Electrical Characteristics for D*n*_GV_{DD}(typ) = 1.8 V

Parameter/Condition	Symbol	Min	Max	Unit	Notes
I/O supply voltage	D*n*_GV_{DD}	1.71	1.89	V	1
I/O reference voltage	MVREFn_{REF}	0.49 × D*n*_GV_{DD}	0.51 × D*n*_GV_{DD}	V	2
I/O termination voltage	V_{TT}	MVREFn_{REF} – 0.04	MVREFn_{REF} + 0.04	V	3
Input high voltage	V_{IH}	MVREFn_{REF} + 0.125	D*n*_GV_{DD} + 0.3	V	—
Input low voltage	V_{IL}	–0.3	MVREFn_{REF} – 0.125	V	—
Output leakage current	I_{OZ}	–9.9	9.9	μA	4
Output high current (V_{OUT} = 1.35 V)	I_{OH}	–13.4	—	mA	—
Output low current (V_{OUT} = 0.280 V)	I_{OL}	13.4	—	mA	—

Notes:
1. D*n*_GV_{DD} is expected to be within 50 mV of the DRAM D*n*_GV_{DD} at all times.
2. MVREFn_{REF} is expected to be equal to 0.5 × D*n*_GV_{DD}, and to track D*n*_GV_{DD} DC variations as measured at the receiver. Peak-to-peak noise on MVREFn_{REF} may not exceed ±2% of the DC value.
3. V_{TT} is not applied directly to the device. It is the supply to which far end signal termination is made and is expected to be equal to MVREFn_{REF}. This rail should track variations in the DC level of MVREFn_{REF}.
4. Output leakage is measured with all outputs disabled, $0 V \le V_{OUT} \le$ D*n*_GV_{DD}.

Table 13 provides the DDR2 capacitance when D*n*_GV_{DD}(typ) = 1.8 V.

Table 13. DDR2 SDRAM Capacitance for D*n*_GV_{DD}(typ) = 1.8 V

Parameter/Condition	Symbol	Min	Max	Unit	Notes
Input/output capacitance: DQ, DQS	C_{IO}	6	8	pF	1

Figure 5 shows the DDR SDRAM output timing for the MCK to MDQS skew measurement (t_{DDKHMH}).

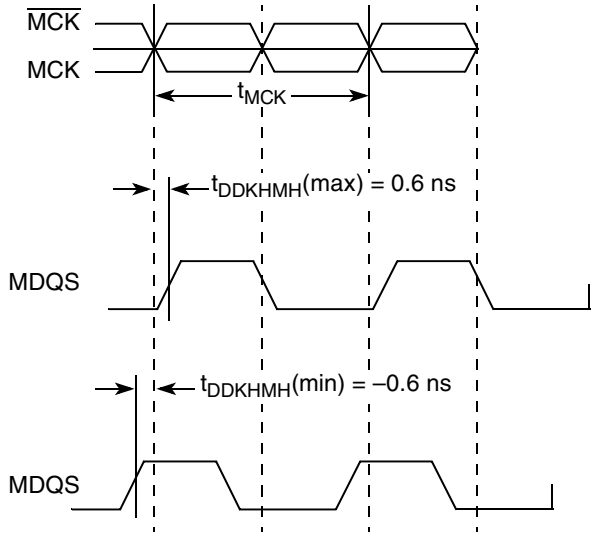


Figure 5. Timing Diagram for t_{DDKHMH}

Figure 6 shows the DDR1 and DDR2 SDRAM output timing diagram.

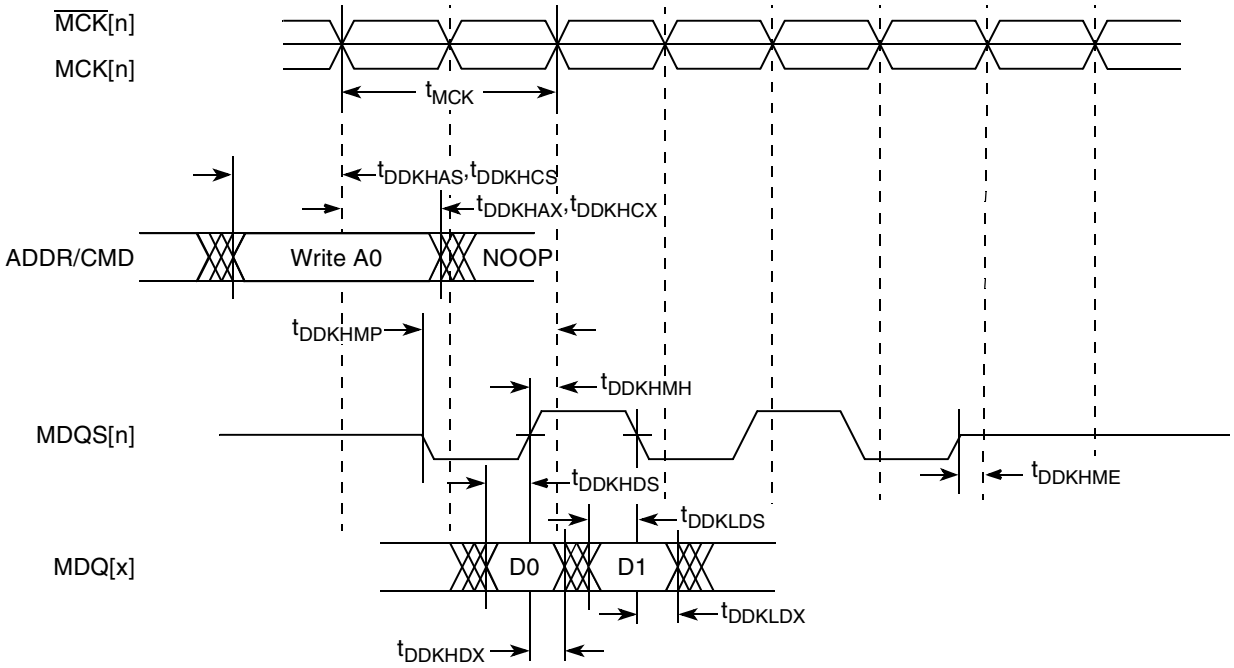


Figure 6. DDR1 and DDR2 SDRAM Output Timing Diagram

Table 26. RMII Receive AC Timing Specifications (continued)

At recommended operating conditions with OV_{DD} of 3.3 V ± 10%.

Parameter/Condition	Symbol[1]	Min	Typical	Max	Unit
REF_CLK clock fall time V_{IH}(max) to V_{IL}(min)	t_{RMXF}	1.0	—	4.0	ns

Note:

1. The symbols used for timing specifications follow the pattern of $t_{\text{(first three letters of functional block)(signal)(state)(reference)(state)}}$ for inputs and $t_{\text{(first two letters of functional block)(reference)(state)(signal)(state)}}$ for outputs. For example, $t_{RMRDVKH}$ symbolizes RMII receive timing (RMR) with respect to the time data input signals (D) reach the valid state (V) relative to the t_{RMX} clock reference (K) going to the high (H) state or setup time. Also, $t_{RMRDXKL}$ symbolizes RMII receive timing (RMR) with respect to the time data input signals (D) went invalid (X) relative to the t_{RMX} clock reference (K) going to the low (L) state or hold time. Note that, in general, the clock reference symbol representation is based on three letters representing the clock of a particular functional. For example, the subscript of t_{RMX} represents the RMII (RM) reference (X) clock. For rise and fall times, the latter convention is used with the appropriate letter: R (rise) or F (fall).

Figure 11 provides the AC test load.

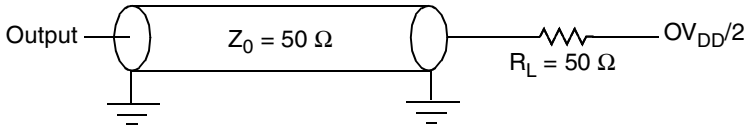


Figure 11. AC Test Load

Figure 12 shows the RMII receive AC timing diagram.

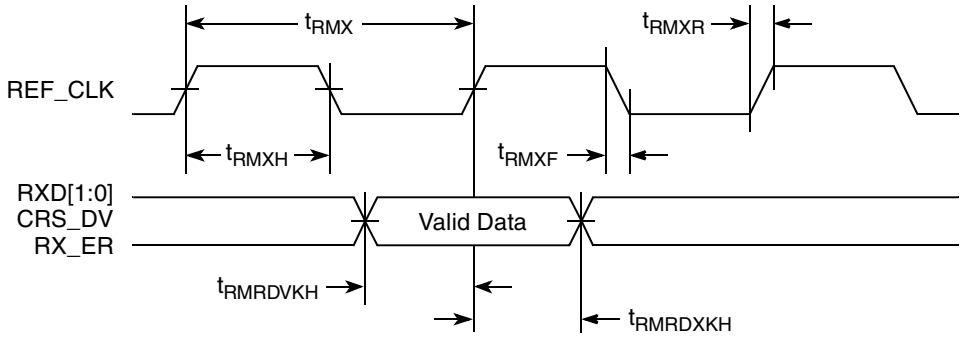


Figure 12. RMII Receive AC Timing Diagram

8.3 Ethernet Management Interface Electrical Characteristics

The electrical characteristics specified here apply to MII management interface signals MDIO (management data input/output) and MDC (management data clock). The electrical characteristics for MII, and RMII are specified in Section 8.1, “Ethernet Controller (10/100 Mbps)—MII/RMII Electrical Characteristics.”

Figure 13 shows the MII management AC timing diagram.

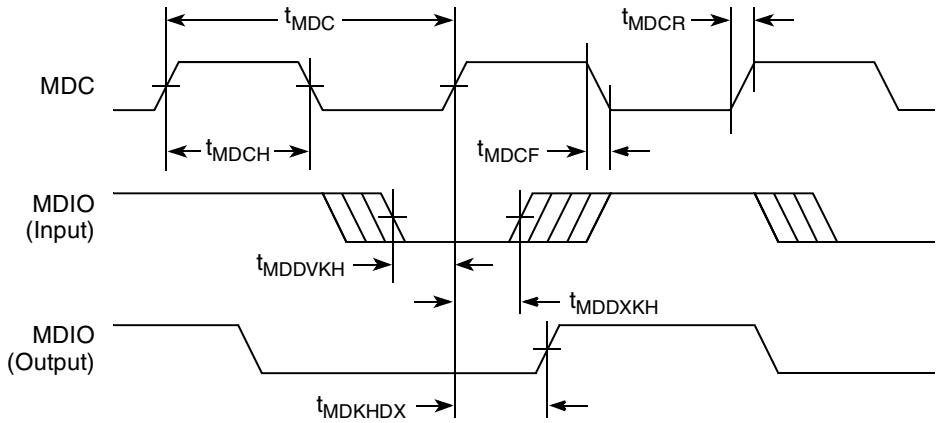


Figure 13. MII Management Interface Timing Diagram

9 Local Bus

This section describes the DC and AC electrical specifications for the local bus interface of the MPC8323E.

9.1 Local Bus DC Electrical Characteristics

Table 29 provides the DC electrical characteristics for the local bus interface.

Table 29. Local Bus DC Electrical Characteristics

Parameter	Symbol	Min	Max	Unit
High-level input voltage	V_{IH}	2	OV_{DD} + 0.3	V
Low-level input voltage	V_{IL}	–0.3	0.8	V
High-level output voltage, I_{OH} = –100 µA	V_{OH}	OV_{DD} – 0.2	—	V
Low-level output voltage, I_{OL} = 100 µA	V_{OL}	—	0.2	V
Input current	I_{IN}	—	±5	µA

9.2 Local Bus AC Electrical Specifications

Table 30 describes the general timing parameters of the local bus interface of the MPC8323E.

Table 30. Local Bus General Timing Parameters

Parameter	Symbol[1]	Min	Max	Unit	Notes
Local bus cycle time	t_{LBK}	15	—	ns	2
Input setup to local bus clock (LCLK*n*)	t_{LBIVKH}	7	—	ns	3, 4
Input hold from local bus clock (LCLK*n*)	t_{LBIXKH}	1.0	—	ns	3, 4
LALE output fall to LAD output transition (LATCH hold time)	$t_{LBOTOT1}$	1.5	—	ns	5

Figure 21 provides the boundary-scan timing diagram.

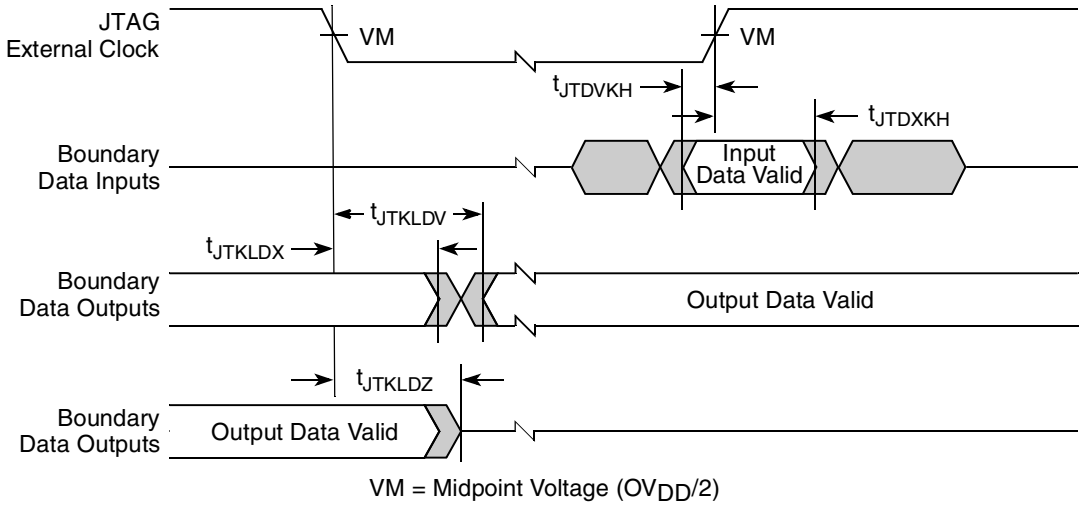


Figure 21. Boundary-Scan Timing Diagram

Figure 22 provides the test access port timing diagram.

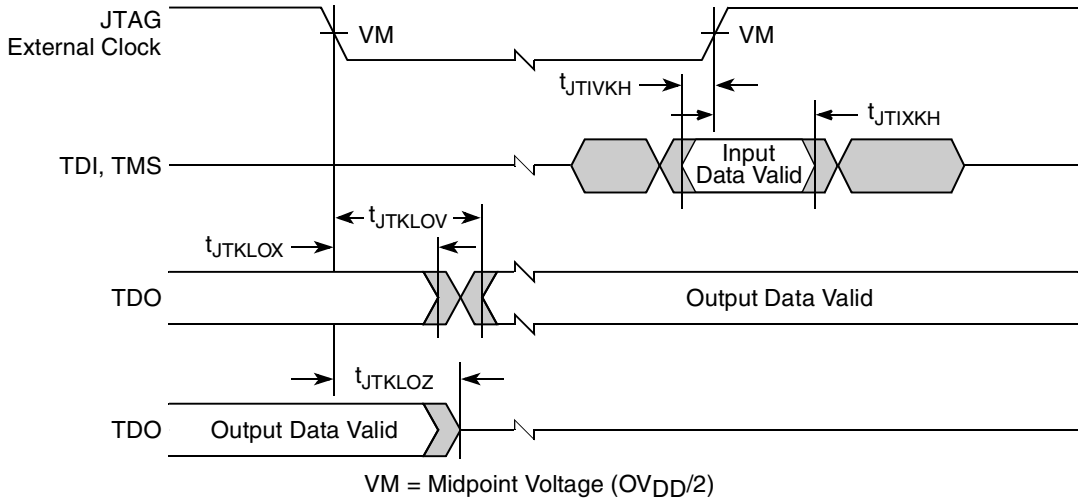


Figure 22. Test Access Port Timing Diagram

12 PCI

This section describes the DC and AC electrical specifications for the PCI bus of the MPC8323E.

12.1 PCI DC Electrical Characteristics

Table 35 provides the DC electrical characteristics for the PCI interface of the MPC8323E.

Table 35. PCI DC Electrical Characteristics[1,2]

Parameter	Symbol	Test Condition	Min	Max	Unit
High-level input voltage	V_{IH}	$V_{OUT} \geq V_{OH}$ (min) or	2	OV_{DD} + 0.3	V
Low-level input voltage	V_{IL}	$V_{OUT} \leq V_{OL}$ (max)	–0.3	0.8	V
High-level output voltage	V_{OH}	OV_{DD} = min, I_{OH} = –100 µA	OV_{DD} – 0.2	—	V
Low-level output voltage	V_{OL}	OV_{DD} = min, I_{OL} = 100 µA	—	0.2	V
Input current	I_{IN}	0 V ≤ V_{IN} ≤ OV_{DD}	—	±5	µA

Notes:
1. Note that the symbol V_{IN}, in this case, represents the OV_{IN} symbol referenced in Table 1 and Table 2.
2. Ranges listed do not meet the full range of the DC specifications of the *PCI 2.3 Local Bus Specifications*.

12.2 PCI AC Electrical Specifications

This section describes the general AC timing parameters of the PCI bus of the MPC8323E. Note that the PCI_CLK or PCI_SYNC_IN signal is used as the PCI input clock depending on whether the MPC8323E is configured as a host or agent device. Table 36 shows the PCI AC timing specifications at 66 MHz.

Table 36. PCI AC Timing Specifications at 66 MHz

Parameter	Symbol[1]	Min	Max	Unit	Notes
Clock to output valid	t_{PCKHOV}	—	6.0	ns	2
Output hold from clock	t_{PCKHOX}	1	—	ns	2
Clock to output high impedence	t_{PCKHOZ}	—	14	ns	2, 3
Input setup to clock	t_{PCIVKH}	3.0	—	ns	2, 4
Input hold from clock	t_{PCIXKH}	0	—	ns	2, 4

Notes:
1. The symbols used for timing specifications follow the pattern of $t_{\text{(first two letters of functional block)(signal)(state)(reference)(state)}}$ for inputs and $t_{\text{(first two letters of functional block)(reference)(state)(signal)(state)}}$ for outputs. For example, t_{PCIVKH} symbolizes PCI timing (PC) with respect to the time the input signals (I) reach the valid state (V) relative to the PCI_SYNC_IN clock, t_{SYS}, reference (K) going to the high (H) state or setup time. Also, t_{PCRHFV} symbolizes PCI timing (PC) with respect to the time hard reset (R) went high (H) relative to the frame signal (F) going to the valid (V) state.
2. See the timing measurement conditions in the *PCI 2.3 Local Bus Specifications*.
3. For purposes of active/float timing measurements, the Hi-Z or off state is defined to be when the total current delivered through the component pin is less than or equal to the leakage current specification.
4. Input timings are measured at the pin.

Figure 27 shows the PCI output AC timing conditions.

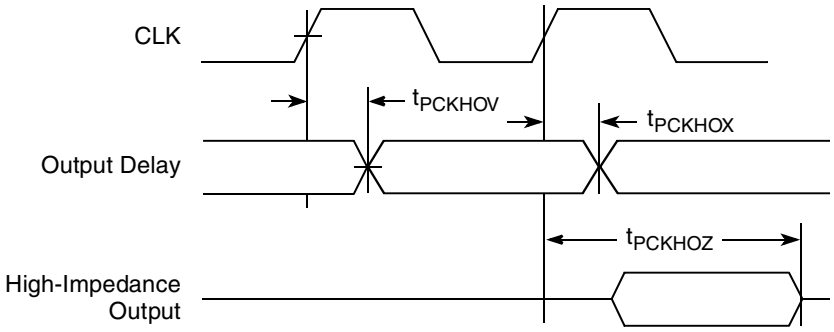


Figure 27. PCI Output AC Timing Measurement Condition

13 Timers

This section describes the DC and AC electrical specifications for the timers of the MPC8323E.

13.1 Timer DC Electrical Characteristics

Table 38 provides the DC electrical characteristics for the MPC8323E timer pins, including TIN, $\overline{\text{TOUT}}$, $\overline{\text{TGATE}}$, and RTC_CLK.

Table 38. Timer DC Electrical Characteristics

Characteristic	Symbol	Condition	Min	Max	Unit
Output high voltage	V_{OH}	I_{OH} = –6.0 mA	2.4	—	V
Output low voltage	V_{OL}	I_{OL} = 6.0 mA	—	0.5	V
Output low voltage	V_{OL}	I_{OL} = 3.2 mA	—	0.4	V
Input high voltage	V_{IH}	—	2.0	OV_{DD} + 0.3	V
Input low voltage	V_{IL}	—	–0.3	0.8	V
Input current	I_{IN}	0 V ≤ V_{IN} ≤ OV_{DD}	—	±5	μA

13.2 Timer AC Timing Specifications

Table 39 provides the timer input and output AC timing specifications.

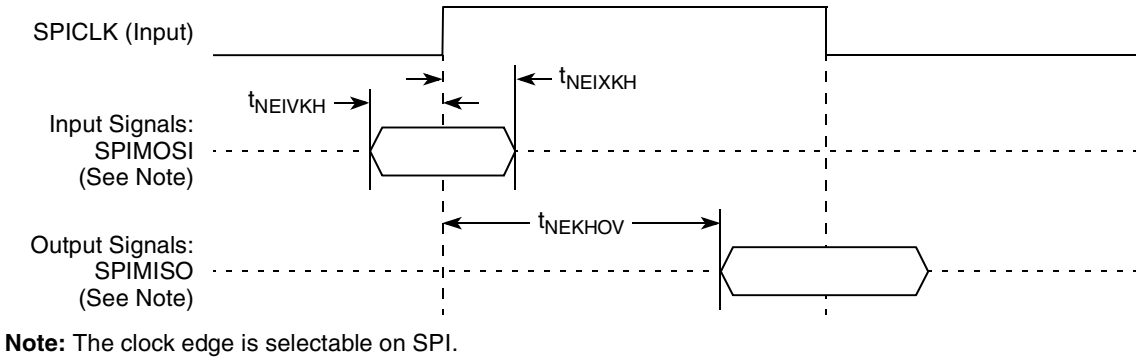
Table 39. Timer Input AC Timing Specifications[1]

Characteristic	Symbol[2]	Min	Unit
Timers inputs—minimum pulse width	t_{TIWID}	20	ns

Notes:
1. Input specifications are measured from the 50% level of the signal to the 50% level of the rising edge of CLKIN. Timings are measured at the pin.
2. Timer inputs and outputs are asynchronous to any visible clock. Timer outputs should be synchronized before use by any external synchronous logic. Timer inputs are required to be valid for at least t_{TIWID} ns to ensure proper operation.

Figure 31 and Figure 32 represent the AC timing from Table 45. Note that although the specifications generally reference the rising edge of the clock, these AC timing diagrams also apply when the falling edge is the active edge.

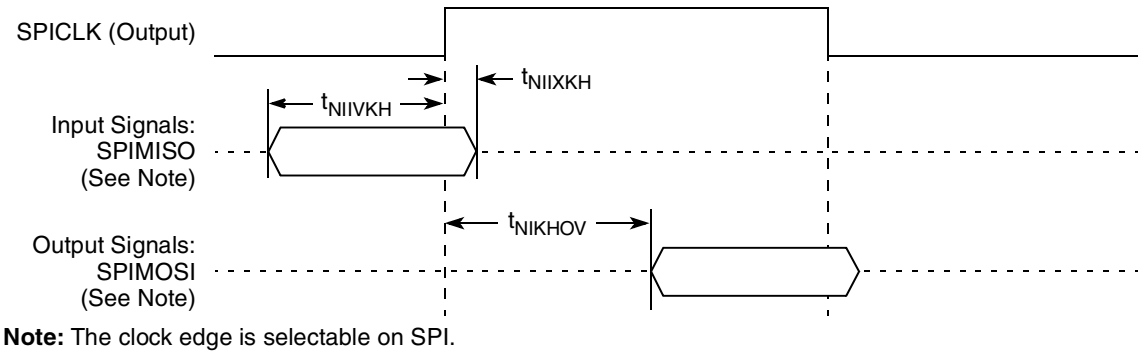
Figure 31 shows the SPI timing in slave mode (external clock).



Note: The clock edge is selectable on SPI.

Figure 31. SPI AC Timing in Slave Mode (External Clock) Diagram

Figure 32 shows the SPI timing in master mode (internal clock).



Note: The clock edge is selectable on SPI.

Figure 32. SPI AC Timing in Master Mode (Internal Clock) Diagram

17 TDM/SI

This section describes the DC and AC electrical specifications for the time-division-multiplexed and serial interface of the MPC8323E.

17.1 TDM/SI DC Electrical Characteristics

Table 46 provides the DC electrical characteristics for the MPC8323E TDM/SI.

Table 46. TDM/SI DC Electrical Characteristics

Characteristic	Symbol	Condition	Min	Max	Unit
Output high voltage	V_{OH}	I_{OH} = –2.0 mA	2.4	—	V
Output low voltage	V_{OL}	I_{OL} = 3.2 mA	—	0.5	V
Input high voltage	V_{IH}	—	2.0	OV_{DD} + 0.3	V

21.3 Pinout Listings

Table 55 shows the pin list of the MPC8323E.

Table 55. MPC8323E PBGA Pinout Listing

Signal	Package Pin Number	Pin Type	Power Supply	Notes
DDR Memory Controller Interface				
MEMC_MDQ0	AE9	IO	GV_{DD}	—
MEMC_MDQ1	AD10	IO	GV_{DD}	—
MEMC_MDQ2	AF10	IO	GV_{DD}	—
MEMC_MDQ3	AF9	IO	GV_{DD}	—
MEMC_MDQ4	AF7	IO	GV_{DD}	—
MEMC_MDQ5	AE10	IO	GV_{DD}	—
MEMC_MDQ6	AD9	IO	GV_{DD}	—
MEMC_MDQ7	AF8	IO	GV_{DD}	—
MEMC_MDQ8	AE6	IO	GV_{DD}	—
MEMC_MDQ9	AD7	IO	GV_{DD}	—
MEMC_MDQ10	AF6	IO	GV_{DD}	—
MEMC_MDQ11	AC7	IO	GV_{DD}	—
MEMC_MDQ12	AD8	IO	GV_{DD}	—
MEMC_MDQ13	AE7	IO	GV_{DD}	—
MEMC_MDQ14	AD6	IO	GV_{DD}	—
MEMC_MDQ15	AF5	IO	GV_{DD}	—
MEMC_MDQ16	AD18	IO	GV_{DD}	—
MEMC_MDQ17	AE19	IO	GV_{DD}	—
MEMC_MDQ18	AF17	IO	GV_{DD}	—
MEMC_MDQ19	AF19	IO	GV_{DD}	—
MEMC_MDQ20	AF18	IO	GV_{DD}	—
MEMC_MDQ21	AE18	IO	GV_{DD}	—
MEMC_MDQ22	AF20	IO	GV_{DD}	—
MEMC_MDQ23	AD19	IO	GV_{DD}	—
MEMC_MDQ24	AD21	IO	GV_{DD}	—
MEMC_MDQ25	AF22	IO	GV_{DD}	—
MEMC_MDQ26	AC21	IO	GV_{DD}	—
MEMC_MDQ27	AF21	IO	GV_{DD}	—
MEMC_MDQ28	AE21	IO	GV_{DD}	—

Table 55. MPC8323E PBGA Pinout Listing (continued)

Signal	Package Pin Number	Pin Type	Power Supply	Notes
MEMC_MDQ29	AD20	IO	GV_{DD}	—
MEMC_MDQ30	AF23	IO	GV_{DD}	—
MEMC_MDQ31	AD22	IO	GV_{DD}	—
MEMC_MDM0	AC9	O	GV_{DD}	—
MEMC_MDM1	AD5	O	GV_{DD}	—
MEMC_MDM2	AE20	O	GV_{DD}	—
MEMC_MDM3	AE22	O	GV_{DD}	—
MEMC_MDQS0	AE8	IO	GV_{DD}	—
MEMC_MDQS1	AE5	IO	GV_{DD}	—
MEMC_MDQS2	AC19	IO	GV_{DD}	—
MEMC_MDQS3	AE23	IO	GV_{DD}	—
MEMC_MBA0	AD16	O	GV_{DD}	—
MEMC_MBA1	AD17	O	GV_{DD}	—
MEMC_MBA2	AE17	O	GV_{DD}	—
MEMC_MA0	AD12	O	GV_{DD}	—
MEMC_MA1	AE12	O	GV_{DD}	—
MEMC_MA2	AF12	O	GV_{DD}	—
MEMC_MA3	AC13	O	GV_{DD}	—
MEMC_MA4	AD13	O	GV_{DD}	—
MEMC_MA5	AE13	O	GV_{DD}	—
MEMC_MA6	AF13	O	GV_{DD}	—
MEMC_MA7	AC15	O	GV_{DD}	—
MEMC_MA8	AD15	O	GV_{DD}	—
MEMC_MA9	AE15	O	GV_{DD}	—
MEMC_MA10	AF15	O	GV_{DD}	—
MEMC_MA11	AE16	O	GV_{DD}	—
MEMC_MA12	AF16	O	GV_{DD}	—
MEMC_MA13	AB16	O	GV_{DD}	—
$\overline{\text{MEMC\_MWE}}$	AC17	O	GV_{DD}	—
$\overline{\text{MEMC\_MRAS}}$	AE11	O	GV_{DD}	—
$\overline{\text{MEMC\_MCAS}}$	AD11	O	GV_{DD}	—
$\overline{\text{MEMC\_MCS}}$	AC11	O	GV_{DD}	—

Table 55. MPC8323E PBGA Pinout Listing (continued)

Signal	Package Pin Number	Pin Type	Power Supply	Notes
MEMC_MCKE	AD14	O	GV_{DD}	3
MEMC_MCK	AF14	O	GV_{DD}	—
$\overline{\text{MEMC\_MCK}}$	AE14	O	GV_{DD}	—
MEMC_MODT	AF11	O	GV_{DD}	—
Local Bus Controller Interface				
LAD0	N25	IO	OV_{DD}	7
LAD1	P26	IO	OV_{DD}	7
LAD2	P25	IO	OV_{DD}	7
LAD3	R26	IO	OV_{DD}	7
LAD4	R25	IO	OV_{DD}	7
LAD5	T26	IO	OV_{DD}	7
LAD6	T25	IO	OV_{DD}	7
LAD7	U25	IO	OV_{DD}	7
LAD8	M24	IO	OV_{DD}	7
LAD9	N24	IO	OV_{DD}	7
LAD10	P24	IO	OV_{DD}	7
LAD11	R24	IO	OV_{DD}	7
LAD12	T24	IO	OV_{DD}	7
LAD13	U24	IO	OV_{DD}	7
LAD14	U26	IO	OV_{DD}	7
LAD15	V26	IO	OV_{DD}	7
LA16	K25	O	OV_{DD}	7
LA17	L25	O	OV_{DD}	7
LA18	L26	O	OV_{DD}	7
LA19	L24	O	OV_{DD}	7
LA20	M26	O	OV_{DD}	7
LA21	M25	O	OV_{DD}	7
LA22	N26	O	OV_{DD}	7
LA23	AC24	O	OV_{DD}	7
LA24	AC25	O	OV_{DD}	7
LA25	AB23	O	OV_{DD}	7
$\overline{\text{LCS0}}$	AB24	O	OV_{DD}	4

Table 55. MPC8323E PBGA Pinout Listing (continued)

Signal	Package Pin Number	Pin Type	Power Supply	Notes
$\overline{\text{LCS1}}$	AB25	O	OV_{DD}	4
$\overline{\text{LCS2}}$	AA23	O	OV_{DD}	4
$\overline{\text{LCS3}}$	AA24	O	OV_{DD}	4
$\overline{\text{LWE0}}$	Y23	O	OV_{DD}	4
$\overline{\text{LWE1}}$	W25	O	OV_{DD}	4
LBCTL	V25	O	OV_{DD}	4
LALE	V24	O	OV_{DD}	7
CFG_RESET_SOURCE[0]/LSDA10/LGPL0	L23	IO	OV_{DD}	—
CFG_RESET_SOURCE[1]/$\overline{\text{LSDWE}}$/LGPL1	K23	IO	OV_{DD}	—
$\overline{\text{LSDRAS}}$/LGPL2/$\overline{\text{LOE}}$	J23	O	OV_{DD}	4
CFG_RESET_SOURCE[2]/$\overline{\text{LSDCAS}}$/LGPL3	H23	IO	OV_{DD}	—
LGPL4/$\overline{\text{LGTA}}$/LUPWAIT/LPBSE	G23	IO	OV_{DD}	4, 8
LGPL5	AC22	O	OV_{DD}	4
LCLK0	Y24	O	OV_{DD}	7
LCLK1	Y25	O	OV_{DD}	7
DUART				
UART_SOUT1/MSRCID0 (DDR ID)/LSRCID0	G1	IO	OV_{DD}	—
UART_SIN1/MSRCID1 (DDR ID)/LSRCID1	G2	IO	OV_{DD}	—
$\overline{\text{UART\_CTS1}}$/MSRCID2 (DDR ID)/LSRCID2	H3	IO	OV_{DD}	—
$\overline{\text{UART\_RTS1}}$/MSRCID3 (DDR ID)/LSRCID3	K3	IO	OV_{DD}	—
UART_SOUT2/MSRCID4 (DDR ID)/LSRCID4	H2	IO	OV_{DD}	—
UART_SIN2/MDVAL (DDR ID)/LDVAL	H1	IO	OV_{DD}	—
$\overline{\text{UART\_CTS2}}$	J3	IO	OV_{DD}	—
$\overline{\text{UART\_RTS2}}$	K4	IO	OV_{DD}	—
I^2C interface				
IIC_SDA/$\overline{\text{CKSTOP\_OUT}}$	AE24	IO	OV_{DD}	2
IIC_SCL/$\overline{\text{CKSTOP\_IN}}$	AF24	IO	OV_{DD}	2
Programmable Interrupt Controller				
$\overline{\text{MCP\_OUT}}$	AD25	O	OV_{DD}	—
$\overline{\text{IRQ0}}$/$\overline{\text{MCP\_IN}}$	AD26	I	OV_{DD}	—
$\overline{\text{IRQ1}}$	K1	IO	OV_{DD}	—
$\overline{\text{IRQ2}}$	K2	I	OV_{DD}	—

Table 55. MPC8323E PBGA Pinout Listing (continued)

Signal	Package Pin Number	Pin Type	Power Supply	Notes
GPIO_PD10/GTM1_TIN2/GTM2_TIN1/CLK17	J24	IO	OV_{DD}	—
GPIO_PD11/$\overline{\text{GTM1\_TGATE2}}$/$\overline{\text{GTM2\_TGATE1}}$	B25	IO	OV_{DD}	—
GPIO_PD12/$\overline{\text{GTM1\_TOUT2}}$/$\overline{\text{GTM2\_TOUT1}}$	C4	IO	OV_{DD}	—
GPIO_PD13/GTM1_TIN3/GTM2_TIN4/BRGO8	D4	IO	OV_{DD}	—
GPIO_PD14/$\overline{\text{GTM1\_TGATE3}}$/$\overline{\text{GTM2\_TGATE4}}$	D5	IO	OV_{DD}	—
GPIO_PD15/$\overline{\text{GTM1\_TOUT3}}$	A5	IO	OV_{DD}	—
GPIO_PD16/GTM1_TIN4/GTM2_TIN3	B5	IO	OV_{DD}	—
GPIO_PD17/$\overline{\text{GTM1\_TGATE4}}$/$\overline{\text{GTM2\_TGATE3}}$	C5	IO	OV_{DD}	—
GPIO_PD18/$\overline{\text{GTM1\_TOUT4}}$/$\overline{\text{GTM2\_TOUT3}}$	A6	IO	OV_{DD}	—
GPIO_PD19/CE_RISC1_INT/CE_EXT_REQ4	B6	IO	OV_{DD}	—
GPIO_PD20/CLK18/BRGO6	D21	IO	OV_{DD}	—
GPIO_PD21/CLK16/BRGO5/UPC1_CLKO	C19	IO	OV_{DD}	—
GPIO_PD22/CLK4/BRGO9/UCC2_CLKO	A7	IO	OV_{DD}	—
GPIO_PD23/CLK3/BRGO10/UCC3_CLKO	B7	IO	OV_{DD}	—
GPIO_PD24/CLK10/BRGO2/UCC4_CLKO	A12	IO	OV_{DD}	—
GPIO_PD25/CLK13/BRGO16/UCC5_CLKO	B10	IO	OV_{DD}	—
GPIO_PD26/CLK2/BRGO4/UCC1_CLKO	E4	IO	OV_{DD}	—
GPIO_PD27/CLK1/BRGO3	F4	IO	OV_{DD}	—
GPIO_PD28/CLK19/BRGO11	D15	IO	OV_{DD}	—
GPIO_PD29/CLK15/BRGO8	C6	IO	OV_{DD}	—
GPIO_PD30/CLK14	D6	IO	OV_{DD}	—
GPIO_PD31/CLK7/BRGO15	E24	IO	OV_{DD}	—
Power and Ground Supplies				
GV_{DD}	AA8, AA10, AA11, AA13, AA14, AA16, AA17, AA19, AA21, AB9, AB10, AB11, AB12, AB14, AB18, AB20, AB21, AC6, AC8, AC14, AC18	GV_{DD}	—	—
OV_{DD}	E5, E6, E8, E9, E10, E12, E14, E15, E16, E18, E19, E20, E22, F5, F6, F8, F10, F14, F16, F19, F22, G22, H5, H6, H21, J5, J22, K21, K22, L5, L6, L22, M5, M22, N5, N21, N22, P6, P22, P23, R5, R23, T5, T21, T22, U6, U22, V5, V22, W22, Y5, AB5, AB6, AC5	OV_{DD}	—	—

22.1 Clocking in PCI Host Mode

When the MPC8323E is configured as a PCI host device (RCWH[PCIHOST] = 1), CLKIN is its primary input clock. CLKIN feeds the PCI clock divider (÷2) and the PCI_SYNC_OUT and PCI_CLK_OUT multiplexors. The CFG_CLKIN_DIV configuration input selects whether CLKIN or CLKIN/2 is driven out on the PCI_SYNC_OUT signal.

PCI_SYNC_OUT is connected externally to PCI_SYNC_IN to allow the internal clock subsystem to synchronize to the system PCI clocks. PCI_SYNC_OUT must be connected properly to PCI_SYNC_IN, with equal delay to all PCI agent devices in the system.

22.1.1 PCI Clock Outputs (PCI_CLK_OUT[0:2])

When the MPC8323E is configured as a PCI host, it provides three separate clock output signals, PCI_CLK_OUT[0:2], for external PCI agents.

When the device comes out of reset, the PCI clock outputs are disabled and are actively driven to a steady low state. Each of the individual clock outputs can be enabled (enable toggling of the clock) by setting its corresponding OCCR[PCICOE*n*] bit. All output clocks are phase-aligned to each other.

22.2 Clocking in PCI Agent Mode

When the MPC8323E is configured as a PCI agent device, PCI_CLK is the primary input clock. In agent mode, the CLKIN signal should be tied to GND, and the clock output signals, PCI_CLK_OUT*n* and PCI_SYNC_OUT, are not used.

22.3 System Clock Domains

As shown in Figure 43, the primary clock input (frequency) is multiplied up by the system phase-locked loop (PLL) and the clock unit to create three major clock domains:

- The coherent system bus clock (*csb_clk*)
- The QUICC Engine clock (*ce_clk*)
- The internal clock for the DDR controller (*ddr_clk*)
- The internal clock for the local bus controller (*lb_clk*)

The *csb_clk* frequency is derived from a complex set of factors that can be simplified into the following equation:

$$csb\_clk = [\text{PCI\_SYNC\_IN} \times (1 + \sim\overline{\text{CFG\_CLKIN\_DIV}})] \times \text{SPMF}$$

In PCI host mode, PCI_SYNC_IN × (1 + ~$\overline{\text{CFG\_CLKIN\_DIV}}$) is the CLKIN frequency.

The *csb_clk* serves as the clock input to the e300c2 core. A second PLL inside the core multiplies up the *csb_clk* frequency to create the internal clock for the core (*core_clk*). The system and core PLL multipliers are selected by the SPMF and COREPLL fields in the reset configuration word low (RCWL) which is loaded at power-on reset or by one of the hard-coded reset options. See the “Reset Configuration” section in the *MPC8323E PowerQUICC II Pro Communications Processor Reference Manual* for more information.

Table 57. Operating Frequencies for PBGA (continued)

Characteristic[1]	Max Operating Frequency	Unit
DDR1/DDR2 memory bus frequency (MCLK)[2]	133	MHz
Local bus frequency (LCLK*n*)[3]	66	MHz
PCI input frequency (CLKIN or PCI_CLK)	66	MHz

1 The CLKIN frequency, RCWL[SPMF], and RCWL[COREPLL] settings must be chosen such that the resulting *csb_clk*, MCLK, LCLK[0:2], and *core_clk* frequencies do not exceed their respective maximum or minimum operating frequencies.
2 The DDR1/DDR2 data rate is 2× the DDR1/DDR2 memory bus frequency.
3 The local bus frequency is 1/2, 1/4, or 1/8 of the *lb_clk* frequency (depending on LCRR[CLKDIV]) which is in turn 1× or 2× the *csb_clk* frequency (depending on RCWL[LBCM]).

22.4 System PLL Configuration

The system PLL is controlled by the RCWL[SPMF] parameter. Table 58 shows the multiplication factor encodings for the system PLL.

NOTE

System PLL VCO frequency = 2 × (CSB frequency) × (System PLL VCO divider).

The VCO divider needs to be set properly so that the System PLL VCO frequency is in the range of 300–600 MHz.

Table 58. System PLL Multiplication Factors

RCWL[SPMF]	System PLL Multiplication Factor
0000	Reserved
0001	Reserved
0010	× 2
0011	× 3
0100	× 4
0101	× 5
0110	× 6
0111–1111	Reserved

As described in Section 22, “Clocking,” the LBCM, DDRCM, and SPMF parameters in the reset configuration word low and the $\overline{\text{CFG\_CLKIN\_DIV}}$ configuration input signal select the ratio between the primary clock input (CLKIN or PCI_CLK) and the internal coherent system bus clock (*csb_clk*). Table 59

shows the expected frequency values for the CSB frequency for select *csb_clk* to CLKIN/PCI_SYNC_IN ratios.

Table 59. CSB Frequency Options

CFG_CLKIN_DIV_B at Reset[1]	SPMF	*csb_clk* : Input Clock Ratio [2]	Input Clock Frequency (MHz)[2]		
			25	33.33	66.67
			csb_clk Frequency (MHz)		
High	0010	2 : 1			133
High	0011	3 : 1		100	
High	0100	4 : 1	100	133	
High	0101	5 : 1	125		
High	0110	6 : 1			
High	0111	7 : 1			
High	1000	8 : 1			
High	1001	9 : 1			
High	1010	10 : 1			
High	1011	11 : 1			
High	1100	12 : 1			
High	1101	13 : 1			
High	1110	14 : 1			
High	1111	15 : 1			
High	0000	16 : 1			
Low	0010	2 : 1			133
Low	0011	3 : 1		100	
Low	0100	4 : 1		133	
Low	0101	5 : 1			
Low	0110	6 : 1			
Low	0111	7 : 1			
Low	1000	8 : 1			
Low	1001	9 : 1			
Low	1010	10 : 1			
Low	1011	11 : 1			
Low	1100	12 : 1			
Low	1101	13 : 1			
Low	1110	14 : 1			
Low	1111	15 : 1			
Low	0000	16 : 1			

1 CFG_CLKIN_DIV_B is only used for host mode; CLKIN must be tied low and CFG_CLKIN_DIV_B must be pulled up (high) in agent mode.

2 CLKIN is the input clock in host mode; PCI_CLK is the input clock in agent mode.

(edge) of the package is approximately the same as the local air temperature near the device. Specifying the local ambient conditions explicitly as the board temperature provides a more precise description of the local ambient conditions that determine the temperature of the device.

At a known board temperature, the junction temperature is estimated using the following equation:

$$T_J = T_B + (R_{\theta JB} \times P_D)$$

where:

T_J = junction temperature (°C)

T_B = board temperature at the package perimeter (°C)

$R_{\theta JB}$ = junction-to-board thermal resistance (°C/W) per JESD51-8

P_D = power dissipation in package (W)

When the heat loss from the package case to the air can be ignored, acceptable predictions of junction temperature can be made. The application board should be similar to the thermal test condition: the component is soldered to a board with internal planes.

23.2.3 Experimental Determination of Junction Temperature

To determine the junction temperature of the device in the application after prototypes are available, the thermal characterization parameter (Ψ_{JT}) can be used to determine the junction temperature with a measurement of the temperature at the top center of the package case using the following equation:

$$T_J = T_T + (\Psi_{JT} \times P_D)$$

where:

T_J = junction temperature (°C)

T_T = thermocouple temperature on top of package (°C)

Ψ_{JT} = thermal characterization parameter (°C/W)

P_D = power dissipation in package (W)

The thermal characterization parameter is measured per JESD51-2 specification using a 40 gauge type T thermocouple epoxied to the top center of the package case. The thermocouple should be positioned so that the thermocouple junction rests on the package. A small amount of epoxy is placed over the thermocouple junction and over about 1 mm of wire extending from the junction. The thermocouple wire is placed flat against the package case to avoid measurement errors caused by cooling effects of the thermocouple wire.

23.2.4 Heat Sinks and Junction-to-Case Thermal Resistance

In some application environments, a heat sink is required to provide the necessary thermal management of the device. When a heat sink is used, the thermal resistance is expressed as the sum of a junction-to-case thermal resistance and a case to ambient thermal resistance:

$$R_{\theta JA} = R_{\theta JC} + R_{\theta CA}$$

where:

$R_{\theta JA}$ = junction-to-ambient thermal resistance (°C/W)

$R_{\theta JC}$ = junction-to-case thermal resistance (°C/W)

$R_{\theta CA}$ = case-to-ambient thermal resistance (°C/W)

$R_{\theta JC}$ is device related and cannot be influenced by the user. The user controls the thermal environment to change the case-to-ambient thermal resistance, $R_{\theta CA}$. For instance, the user can change the size of the heat sink, the air flow around the device, the interface material, the mounting arrangement on printed-circuit board, or change the thermal dissipation on the printed-circuit board surrounding the device.

To illustrate the thermal performance of the devices with heat sinks, the thermal performance has been simulated with a few commercially available heat sinks. The heat sink choice is determined by the application environment (temperature, air flow, adjacent component power dissipation) and the physical space available. Because there is not a standard application environment, a standard heat sink is not required.

Accurate thermal design requires thermal modeling of the application environment using computational fluid dynamics software which can model both the conduction cooling and the convection cooling of the air moving through the application. Simplified thermal models of the packages can be assembled using the junction-to-case and junction-to-board thermal resistances listed in the thermal resistance table. More detailed thermal models can be made available on request.

Heat sink vendors include the following list:

Aavid Thermalloy 603-224-9988
80 Commercial St.
Concord, NH 03301
Internet: www.aavidthermalloy.com

Alpha Novatech 408-567-8082
473 Sapena Ct. #12
Santa Clara, CA 95054
Internet: www.alphanovatech.com

International Electronic Research Corporation (IERC) 818-842-7277
413 North Moss St.
Burbank, CA 91502
Internet: www.ctscorp.com

Millennium Electronics (MEI) 408-436-8770
Loroco Sites
671 East Brokaw Road
San Jose, CA 95112
Internet: www.mei-thermal.com

Tyco Electronics 800-522-2800
Chip Coolers™
P.O. Box 3668
Harrisburg, PA 17105-3668
Internet: www.chipcoolers.com

Table 67. Document Revision History

Rev. No.	Date	Substantive Change(s)
2	4/2008	• Removed Figures 2 and 3 overshoot and undershoot voltage specs from Section 2.1.2, "Power Supply Voltage Specification," and footnotes 4 and 5 from Table 1. • Corrected QUIESCE signal to be an output signal in Table 55. • Added column for GVDD (1.8 V) - DDR2 - to Table 6 with 0.212-W typical power dissipation. • Added Figure 4 DDR input timing diagram. • Removed CE_TRB* and CE_PIO* signals from Table 55. • Added three local bus AC specifications to Table 30 (duty cycle, jitter, delay between input clock and local bus clock). • Added row in Table 2 stating junction temperature range of 0 to 105•C. • Modified Section 2.2, "Power Sequencing," to include $\overline{\text{PORESET}}$ requirement.
1	6/2007	Correction to descriptive text in Section 2.2.
0	6/2007	Initial release.